优尚

YOUSHANG SEMICONDUCTOR

设计研发新型功率器件

各类小信号开关

中低压及高压大电流等场效应管

0755-83047638
ysbdt@szyoushang.cn
www.szyoushang.cn

企业微信二维码

企业QQ二维码

Description

The DIODES™ NK-AZ1117I is a low dropout three-terminal regulator optimized for a low voltage where transient response and minimum input voltage are critical. The device provides current-limit and thermal-shutdown features. Its circuit includes a trimmed bandgap reference to assure an output voltage accuracy of within ±1%. On-chip thermal shutdown provides protection against a combination of high current and ambient temperature that may create excessive junction temperature.

The NK-AZ1117I is available in 1.2V, 1.5V, 1.8V, 2.5V, 3.3V, and 5 .0V fixed output voltage versions and an ADJ output voltage version. The fixed versions integrate the adjust resistors. It is also available in an adjustable version which can set the output voltage with two external resistors.

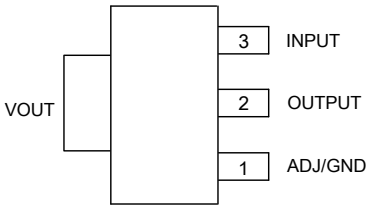
The NK-AZ1117I is available in the industry-standard SOT223 and TO252-2 packages.

Features

- Current Limit: 1.35A (Typ)
- Output Noise from 10Hz to 10KHz: 0.003% of V_{OUT}
- PSRR at I_{OUT} = 300mA and f = 120Hz: 70dB
- Output Voltage Accuracy: ±1% (Except 1.2V Version)
- On-chip Thermal Shutdown
- Maximum Quiescent Current: I_{QMAX} = 6mA
- Compatible with Low ESR Ceramic Capacitor
- Operation Junction Temperature: -40°C to +125°C

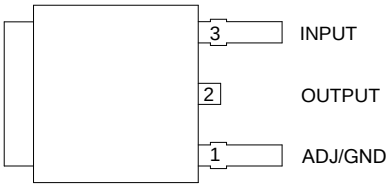
Pin Assignments

(Top View)



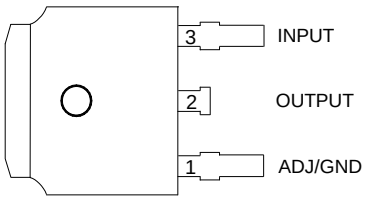
SOT223

(Top View)



TO252-2

(Top View)

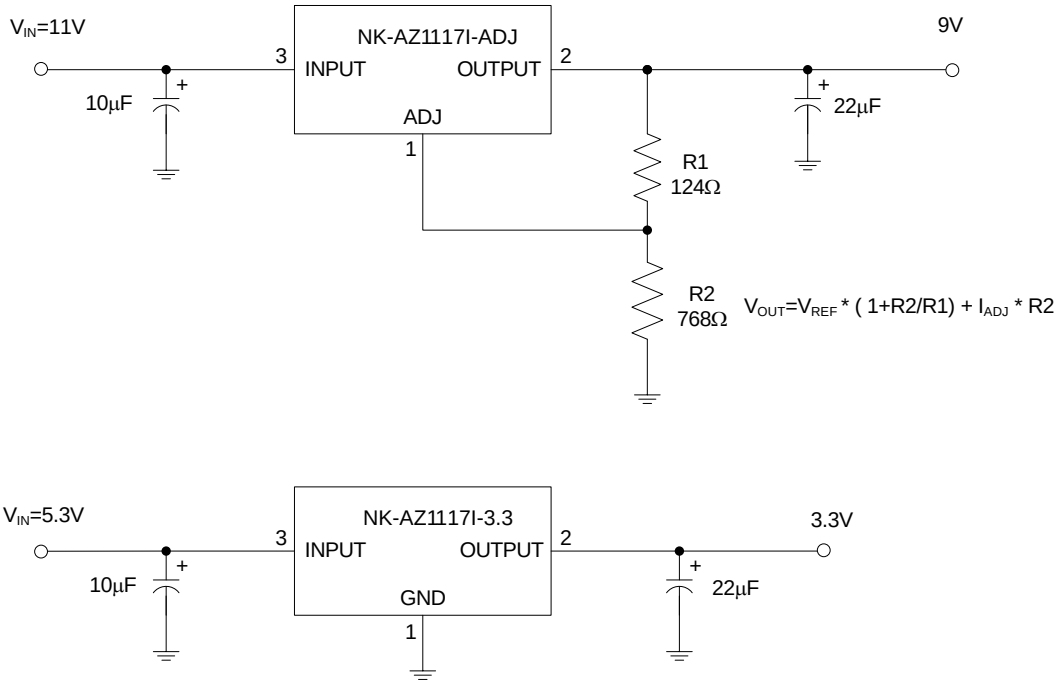


TO252 (Type CJ)

Applications

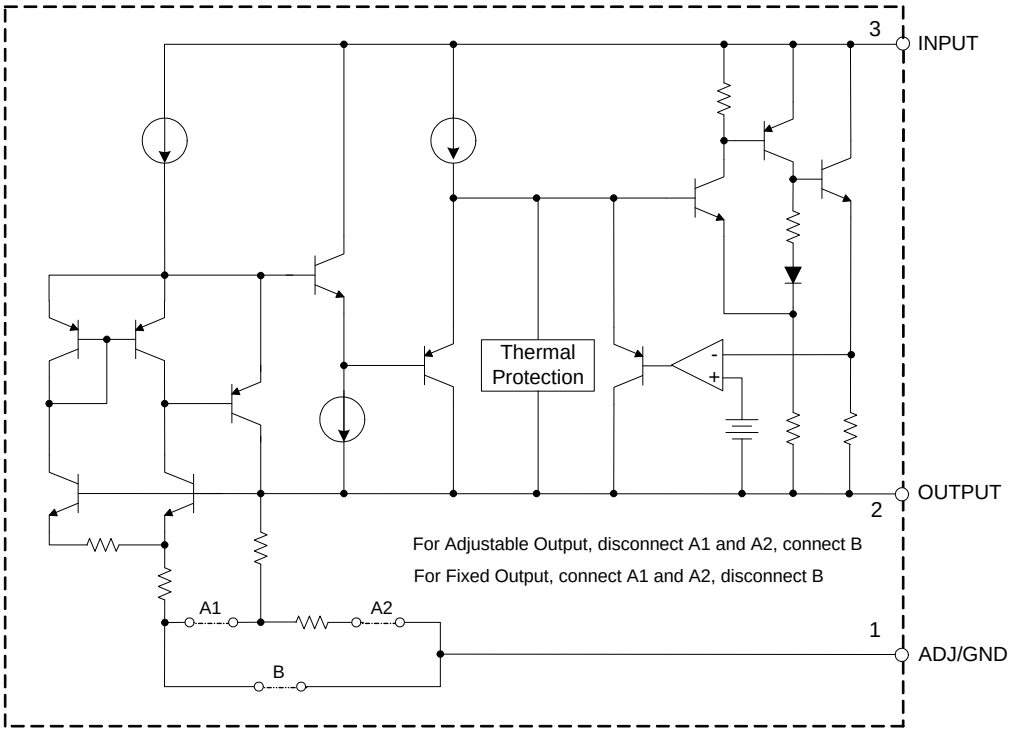
- USB devices
- Add-on cards
- DVD players
- PC motherboards

Typical Applications Circuit (Note 4)



Note: 4. The NK-AZ1117I is compatible with low ESR ceramic capacitor. The ESR of the output capacitors must be less than 20Ω. A minimum of 10μF output capacitor is required.

Functional Block Diagram



Absolute Maximum Ratings (Note 5) (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Rating		Unit
V_{IN}	Input Voltage	18		V
T_J	Operating Junction Temperature Range	+150		°C
T_{STG}	Storage Temperature Range	-65 to +150		°C
θ_{JA}	Thermal Resistance (Without Heatsink)	SOT223	125	°C/W
		TO252-2	100	
θ_{JA}	Thermal Resistance (With Heatsink) (Note 6)	SOT223	100	°C/W
		TO252-2	70	
T_{LEAD}	Lead Temperature (Soldering, 10sec)	+260		°C

Notes: 5. Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.
6. Chip is soldered to 100mm^2(10mm*10mm) copper (top side solder mask) on 2oz.2 layers FR-4 PCB with 8*0.5mm vias.

Recommended Operating Conditions (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Min	Max	Unit
V_{IN}	Input Voltage	–	15	V
T_J	Operating Junction Temperature Range	-40	+125	°C

Electrical Characteristics NK-AZ1117I-ADJ

(Operating Conditions: V_{IN} = V_{OUT}+2V, I_{OUT} = 10mA, T_J = +25°C, unless otherwise specified. (P ≤ maximum power dissipation). Limits appearing in **Boldface** type apply over the entire junction temperature range for operation, -40°C to +125°C.)

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
V_{REF}	Reference Voltage	1.5V ≤ V_{IN}-V_{OUT} ≤ 10V		1.238	1.250	1.262	V
				1.225	1.250	**1.275**	
V_{RLINE}	Line Regulation	1.5V ≤ V_{IN}-V_{OUT} ≤ 10V		—	0.001	0.1	%
				—	—	**0.2**	
V_{RLOAD}	Load Regulation	V_{IN} = V_{OUT}+2V 1mA ≤ I_{OUT} ≤ 1A		—	0.4	1.0	%
V_{DROP}	Dropout Voltage	ΔV_{REF} = 1%, I_{OUT} = 0.8A	SOT223	—	1.2	1.3	V
			TO252-2	—	1.3	1.4	V
I_{LIMIT}	Current Limit	—		1	1.35	—	A
—	Adjust Pin Current	—		—	60	**120**	μA
—	Adjust Pin Current Change	1.5 ≤ (V_{IN}-V_{OUT}) ≤ 10V		—	0.2	**5**	μA
—	Minimum Load Current	1.5 ≤ (V_{IN}-V_{OUT}) ≤ 10V		—	1.7	**5**	mA
PSRR	Ripple Rejection	f = 120Hz, C_{OUT} = 22μF (V_{IN}-V_{OUT}) = 3V, I_{OUT} = 300mA		—	70	—	dB
—	Temperature Stability	—		—	0.5	—	%
—	RMS Output Noise (% of V_{OUT})	T_A = +25°C, 10Hz ≤ f ≤ 10KHz		—	0.003	—	%
—	Thermal Shutdown	Junction Temperature		—	+160	—	°C
—	Thermal Shutdown Hysteresis	—		—	+16	—	°C
θ_{JC}	Thermal Resistance (Junction to Case)	SOT223		—	15	—	°C/W
				—		—	
		TO252-2		—	10	—	

Electrical Characteristics NK-AZ1117I-1.2

(Operating Conditions: V_{IN} ≤ 10V, I_{OUT} = 10mA, T_J = +25°C, unless otherwise specified. (P ≤ maximum power dissipation). Limits appearing in **Boldface** type apply over the entire junction temperature range for operation, -40°C to +125°C.)

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
V_{OUT}	Output Voltage	1.5V ≤ V_{IN}-V_{OUT} ≤ 10V		1.176	1.2	1.224	V
				1.152	1.2	**1.248**	
V_{RLINE}	Line Regulation	1.5V ≤ V_{IN}-V_{OUT} ≤ 10V		—	0.5	6	mV
				—	—	**10**	
V_{RLOAD}	Load Regulation	V_{IN} = V_{OUT}+2V 1mA ≤ I_{OUT} ≤ 1A		—	2	15	mV
V_{DROP}	Dropout Voltage	ΔV_{OUT} = 1%, I_{OUT} = 0.8A	SOT223	—	1.2	1.3	V
			TO252-2	—	1.3	1.4	V
I_{LIMIT}	Current Limit	—		1	1.35	—	A
I_Q	Quiescent Current	I_{OUT} = 0		—	4	**6**	mA
PSRR	Ripple Rejection	f = 120Hz, C_{OUT} = 22μF (V_{IN}-V_{OUT}) = 3V, I_{OUT} = 300mA		—	70	—	dB
—	Temperature Stability	—		—	0.5	—	%
—	RMS Output Noise (% of V_{OUT})	T_A = +25°C, 10Hz ≤ f ≤ 10KHz		—	0.003	—	%
—	Thermal Shutdown	Junction Temperature		—	+160	—	°C
—	Thermal Shutdown Hysteresis	—		—	+16	—	°C
θ_{JC}	Thermal Resistance (Junction to Case)	SOT223		—	15	—	°C/W
				—		—	
		TO252-2		—	10	—	

Electrical Characteristics NK-AZ1117I-1.5

(Operating Conditions: V_{IN} ≤ 10V, I_{OUT} = 10mA, T_J = +25°C, unless otherwise specified. (P ≤ maximum power dissipation). Limits appearing in **Boldface** type apply over the entire junction temperature range for operation, -40°C to +125°C.)

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
V_{OUT}	Output Voltage	1.5V ≤ V_{IN}-V_{OUT} ≤ 10V		1.485	1.5	1.515	V
				1.47	1.5	**1.53**	
V_{RLINE}	Line Regulation	1.5V ≤ V_{IN}-V_{OUT} ≤ 10V		—	0.5	6	mV
				—	—	**10**	
V_{RLOAD}	Load Regulation	V_{IN} = V_{OUT}+2V 1mA ≤ I_{OUT} ≤ 1A		—	2	15	mV
V_{DROP}	Dropout Voltage	ΔV_{OUT} = 1%, I_{OUT} = 0.8A	SOT223	—	1.2	1.3	V
			TO252-2	—	1.3	1.4	V
I_{LIMIT}	Current Limit	—		1	1.35	—	A
I_Q	Quiescent Current	I_{OUT} = 0		—	4	**6**	mA
PSRR	Ripple Rejection	f = 120Hz, C_{OUT} = 22μF (V_{IN}-V_{OUT}) = 3V, I_{OUT} = 300mA		—	70	—	dB
—	Temperature Stability	—		—	0.5	—	%
—	RMS Output Noise (% of V_{OUT})	T_A = +25°C, 10Hz ≤ f ≤ 10KHz		—	0.003	—	%
—	Thermal Shutdown	Junction Temperature		—	+160	—	°C
—	Thermal Shutdown Hysteresis	—		—	+16	—	°C
θ_{JC}	Thermal Resistance (Junction to Case)	SOT223		—	15	—	°C/W
				—		—	
		TO252-2		—	10	—	

Electrical Characteristics NK-AZ1117I-1.8

(Operating Conditions: V_{IN} ≤ 10V, I_{OUT} = 10mA, T_J = +25°C, unless otherwise specified. (P ≤ maximum power dissipation). Limits appearing in **Boldface** type apply over the entire junction temperature range for operation, -40°C to +125°C.)

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
V_{OUT}	Output Voltage	1.5V ≤ V_{IN}-V_{OUT} ≤ 10V		1.782	1.8	1.818	V
				1.764	1.8	**1.836**	
V_{RLINE}	Line Regulation	1.5V ≤ V_{IN}-V_{OUT} ≤ 10V		—	0.5	6	mV
				—	—	**10**	
V_{RLOAD}	Load Regulation	V_{IN} = V_{OUT}+2V 1mA ≤ I_{OUT} ≤ 1A		—	2	15	mV
V_{DROP}	Dropout Voltage	ΔV_{OUT} = 1%, I_{OUT} = 0.8A	SOT223	—	1.2	1.3	V
			TO252-2	—	1.3	1.4	V
I_{LIMIT}	Current Limit	—		1	1.35	—	A
I_Q	Quiescent Current	I_{OUT} = 0		—	4	**6**	mA
PSRR	Ripple Rejection	f = 120Hz, C_{OUT} = 22μF (V_{IN}-V_{OUT}) = 3V, I_{OUT} = 300mA		—	70	—	dB
—	Temperature Stability	—		—	0.5	—	%
—	RMS Output Noise (% of V_{OUT})	T_A = +25°C, 10Hz ≤ f ≤ 10KHz		—	0.003	—	%
—	Thermal Shutdown	Junction Temperature		—	+160	—	°C
—	Thermal Shutdown Hysteresis	—		—	+16	—	°C
θ_{JC}	Thermal Resistance (Junction to Case)	SOT223		—	15	—	°C/W
				—		—	
		TO252-2		—	10	—	

Electrical Characteristics NK-AZ1117I-2.5

(Operating Conditions: V_{IN} ≤ 10V, I_{OUT} = 10mA, T_J = +25°C, unless otherwise specified. (P ≤ maximum power dissipation). Limits appearing in **Boldface** type apply over the entire junction temperature range for operation, -40°C to +125°C.)

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
V_{OUT}	Output Voltage	1.5V ≤ V_{IN}-V_{OUT} ≤ 10V		2.475	2.5	2.525	V
				2.455	**2.5**	**2.545**	
V_{RLINE}	Line Regulation	1.5V ≤ V_{IN}-V_{OUT} ≤ 10V		—	0.5	6	mV
				—	—	**10**	
V_{RLOAD}	Load Regulation	V_{IN} = V_{OUT}+2V 1mA ≤ I_{OUT} ≤ 1A		—	2	15	mV
V_{DROP}	Dropout Voltage	ΔV_{OUT} = 1%, I_{OUT} = 0.8A	SOT223	—	1.2	1.3	V
			TO252-2	—	1.3	1.4	V
I_{LIMIT}	Current Limit	—		1	1.35	—	A
I_Q	Quiescent Current	I_{OUT} = 0		—	4	**6**	mA
PSRR	Ripple Rejection	f = 120Hz, C_{OUT} = 22μF (V_{IN}-V_{OUT}) = 3V, I_{OUT} = 300mA		—	70	—	dB
—	Temperature Stability	—		—	0.5	—	%
—	RMS Output Noise (% of V_{OUT})	T_A = +25°C, 10Hz ≤ f ≤ 10KHz		—	0.003	—	%
—	Thermal Shutdown	Junction Temperature		—	+160	—	°C
—	Thermal Shutdown Hysteresis	—		—	+16	—	°C
θ_{JC}	Thermal Resistance (Junction to Case)	SOT223		—	15	—	°C/W
				—		—	
		TO252-2		—	10	—	

Electrical Characteristics NK-AZ1117I-3.3

(Operating Conditions: $V_{IN} \leq 10V$, I_{OUT} = 10mA, T_J = +25°C, unless otherwise specified. (P ≤ maximum power dissipation). Limits appearing in **Boldface** type apply over the entire junction temperature range for operation, -40°C to +125°C.)

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
V_{OUT}	Output Voltage	1.5V ≤ V_{IN}-V_{OUT} ≤ 10V		3.267	3.3	3.333	V
				3.235	3.3	**3.365**	
V_{RLINE}	Line Regulation	1.5V ≤ V_{IN}-V_{OUT} ≤ 10V		—	0.5	6	mV
				—	—	**10**	
V_{RLOAD}	Load Regulation	V_{IN} = V_{OUT}+2V 1mA ≤ I_{OUT} ≤ 1A		—	2	15	mV
V_{DROP}	Dropout Voltage	ΔV_{OUT} = 1%, I_{OUT} = 0.8A	SOT223	—	1.2	1.3	V
			TO252-2	—	1.3	1.4	V
I_{LIMIT}	Current Limit	—		1	1.35	—	A
I_Q	Quiescent Current	I_{OUT} = 0		—	4	**6**	mA
PSRR	Ripple Rejection	f = 120Hz, C_{OUT} = 22μF (V_{IN}-V_{OUT}) = 3V, I_{OUT} = 300mA		—	70	—	dB
—	Temperature Stability	—		—	0.5	—	%
—	RMS Output Noise (% of V_{OUT})	T_A = +25ºC, 10Hz ≤ f ≤ 10KHz		—	0.003	—	%
—	Thermal Shutdown	Junction Temperature		—	+160	—	°C
—	Thermal Shutdown Hysteresis	—		—	+16	—	°C
θ_{JC}	Thermal Resistance (Junction to Case)	SOT223		—	15	—	°C/W
				—		—	
		TO252-2		—	10	—	

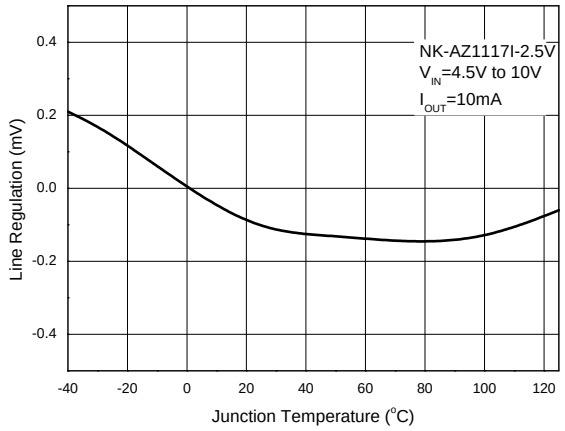
Electrical Characteristics NK-AZ1117I-5.0

(Operating Conditions: $V_{IN} \leq 10V$, I_{OUT} = 10mA, T_J = +25°C, unless otherwise specified. (P ≤ maximum power dissipation). Limits appearing in **Boldface** type apply over the entire junction temperature range for operation, -40°C to +125°C.)

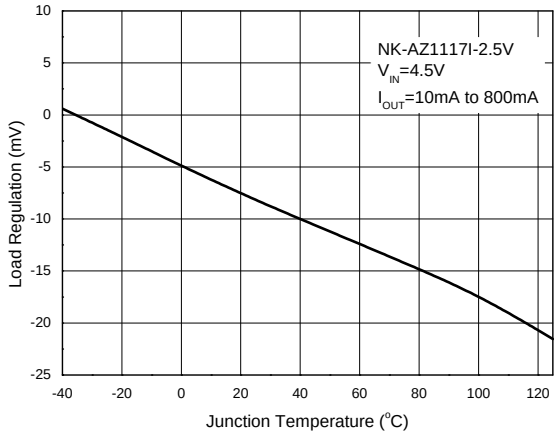
Symbol	Parameter	Conditions		Min	Typ	Max	Unit
V_{OUT}	Output Voltage	1.5V ≤ V_{IN}-V_{OUT} ≤ 10V		4.950	5.0	5.050	V
				4.900	5.0	**5.100**	
V_{RLINE}	Line Regulation	1.5V ≤ V_{IN}-V_{OUT} ≤ 10V		—	0.5	6	mV
				—	—	**10**	
V_{RLOAD}	Load Regulation	V_{IN} = V_{OUT}+2V 1mA ≤ I_{OUT} ≤ 1A		—	2	15	mV
V_{DROP}	Dropout Voltage	ΔV_{OUT} = 1%, I_{OUT} = 0.8A	SOT223	—	1.2	1.3	V
			TO252-2	—	1.3	1.4	V
I_{LIMIT}	Current Limit	—		1	1.35	—	A
I_Q	Quiescent Current	I_{OUT} = 0		—	4	**6**	mA
PSRR	Ripple Rejection	f = 120Hz, C_{OUT} = 22μF (V_{IN}-V_{OUT}) = 3V, I_{OUT} = 300mA		—	70	—	dB
—	Temperature Stability	—		—	0.5	—	%
—	RMS Output Noise (% of V_{OUT})	T_A = +25°C, 10Hz ≤ f ≤ 10KHz		—	0.003	—	%
—	Thermal Shutdown	Junction Temperature		—	+160	—	°C
—	Thermal Shutdown Hysteresis	—		—	+16	—	°C
θ_{JC}	Thermal Resistance (Junction to Case)	SOT223		—	15	—	°C/W
		TO252-2		—	10	—	

Performance Characteristics

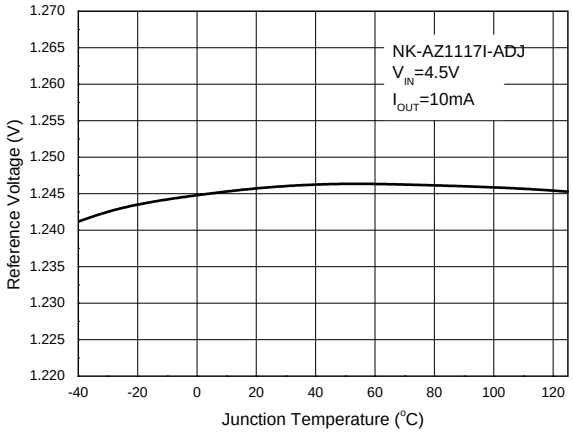
Line Regulation vs. Temperature



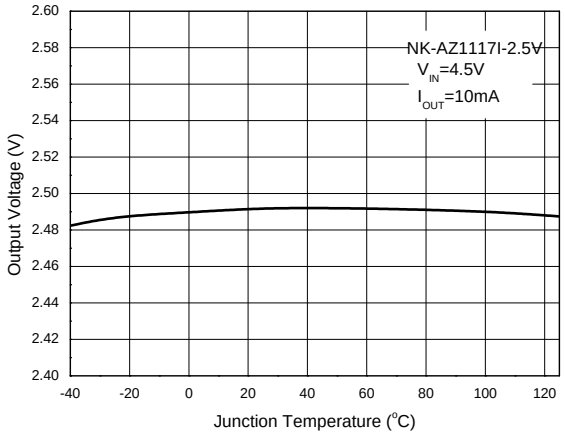
Load Regulation vs. Temperature



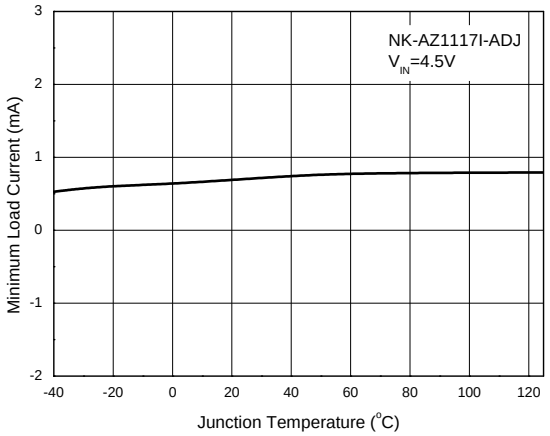
Reference Voltage vs. Temperature



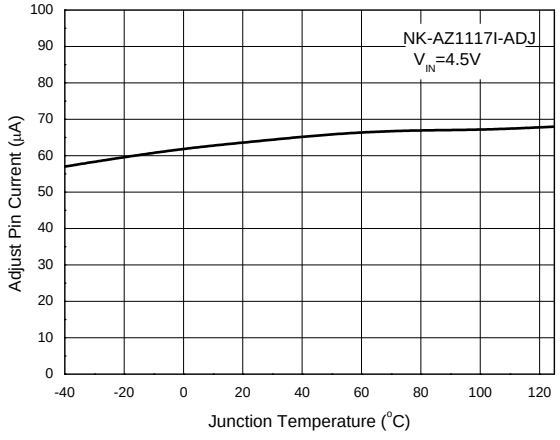
Output Voltage vs. Temperature



Minimum Load Current vs. Temperature

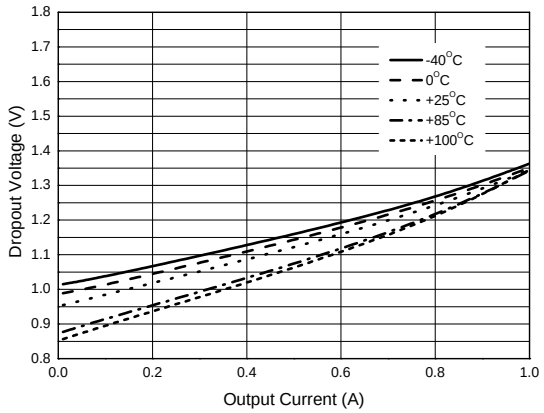


Adjust Pin Current vs. Temperature

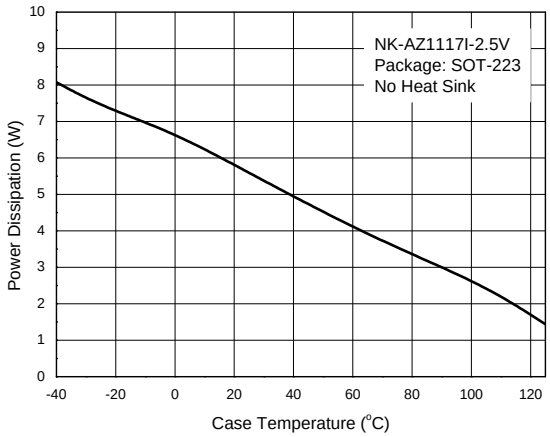


Performance Characteristics (continued)

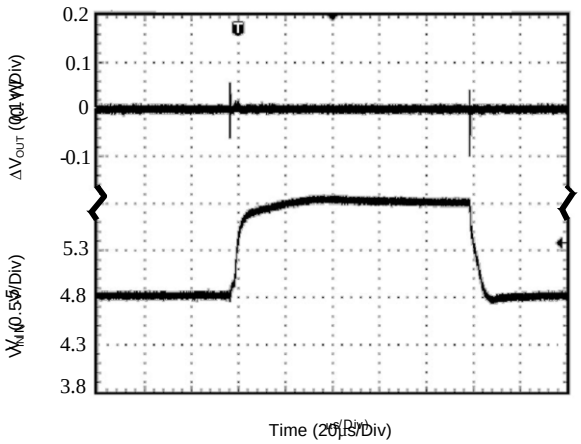
Dropout Voltage vs. Output Current



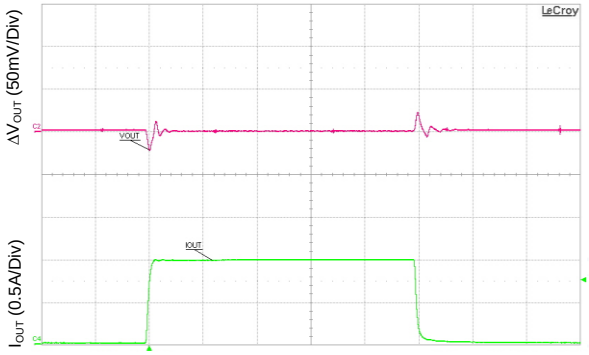
Power Dissipation vs. Temperature



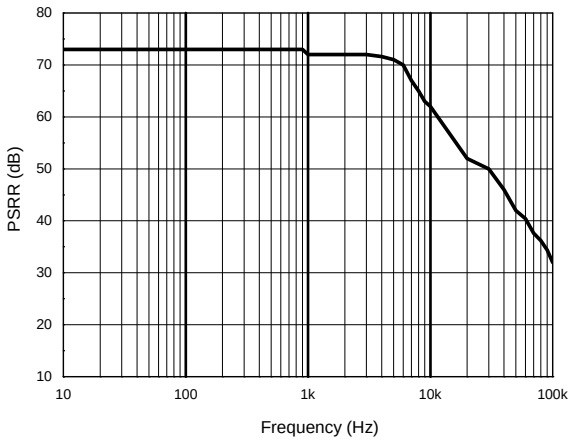
Line Transient Response



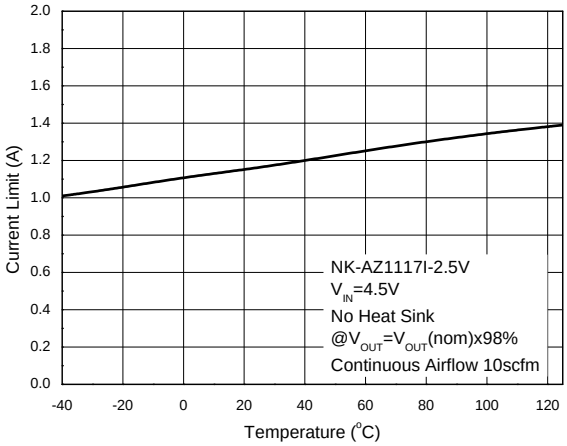
Load Transient Response



PSRR vs. Frequency

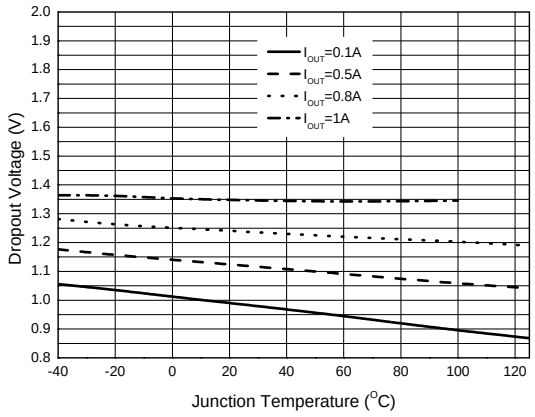


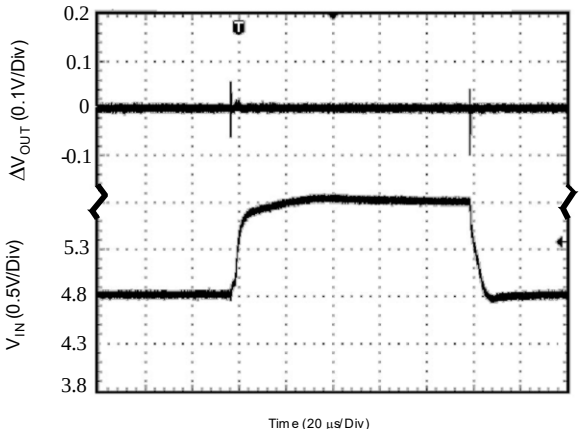
Current Limit vs. Temperature

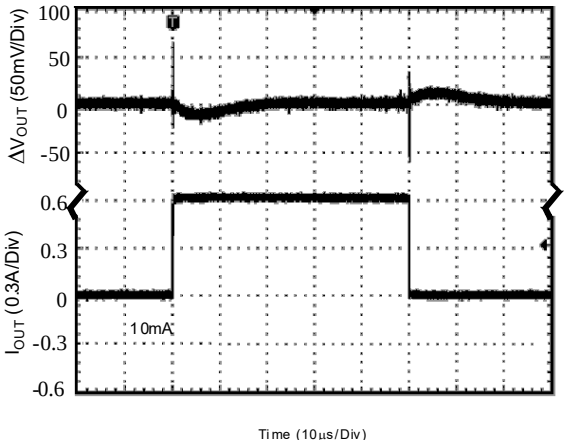


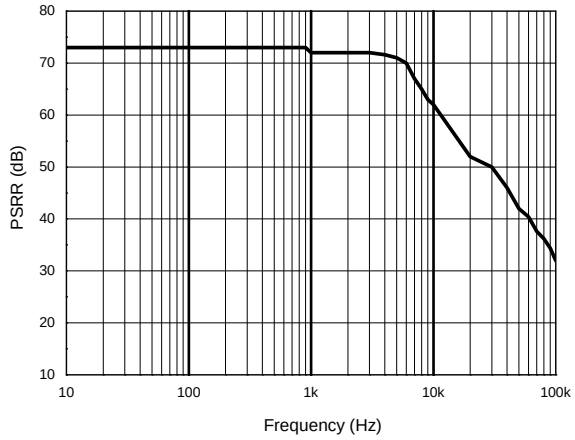
Performance Characteristics (continued)

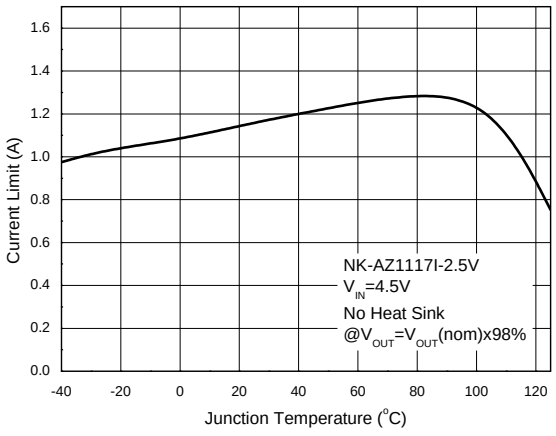
Dropout Voltage vs. Temperature





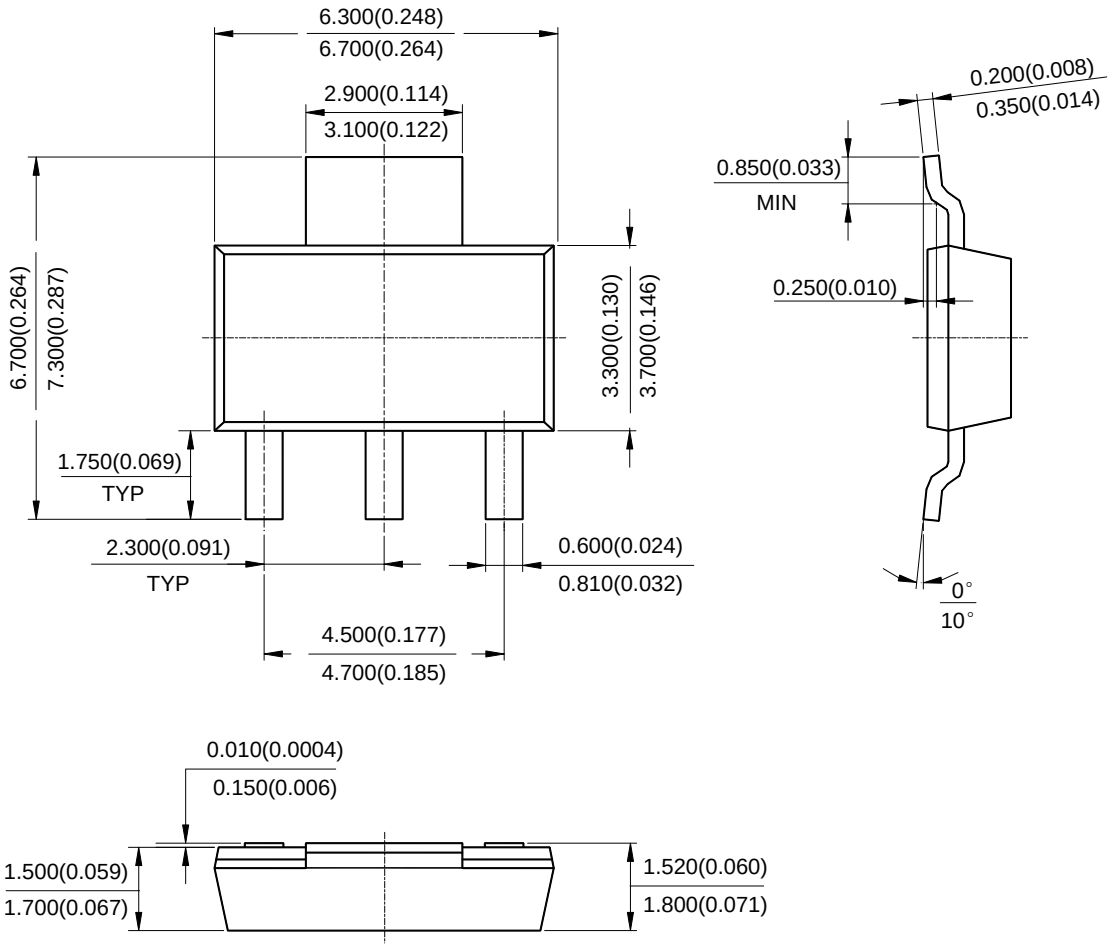






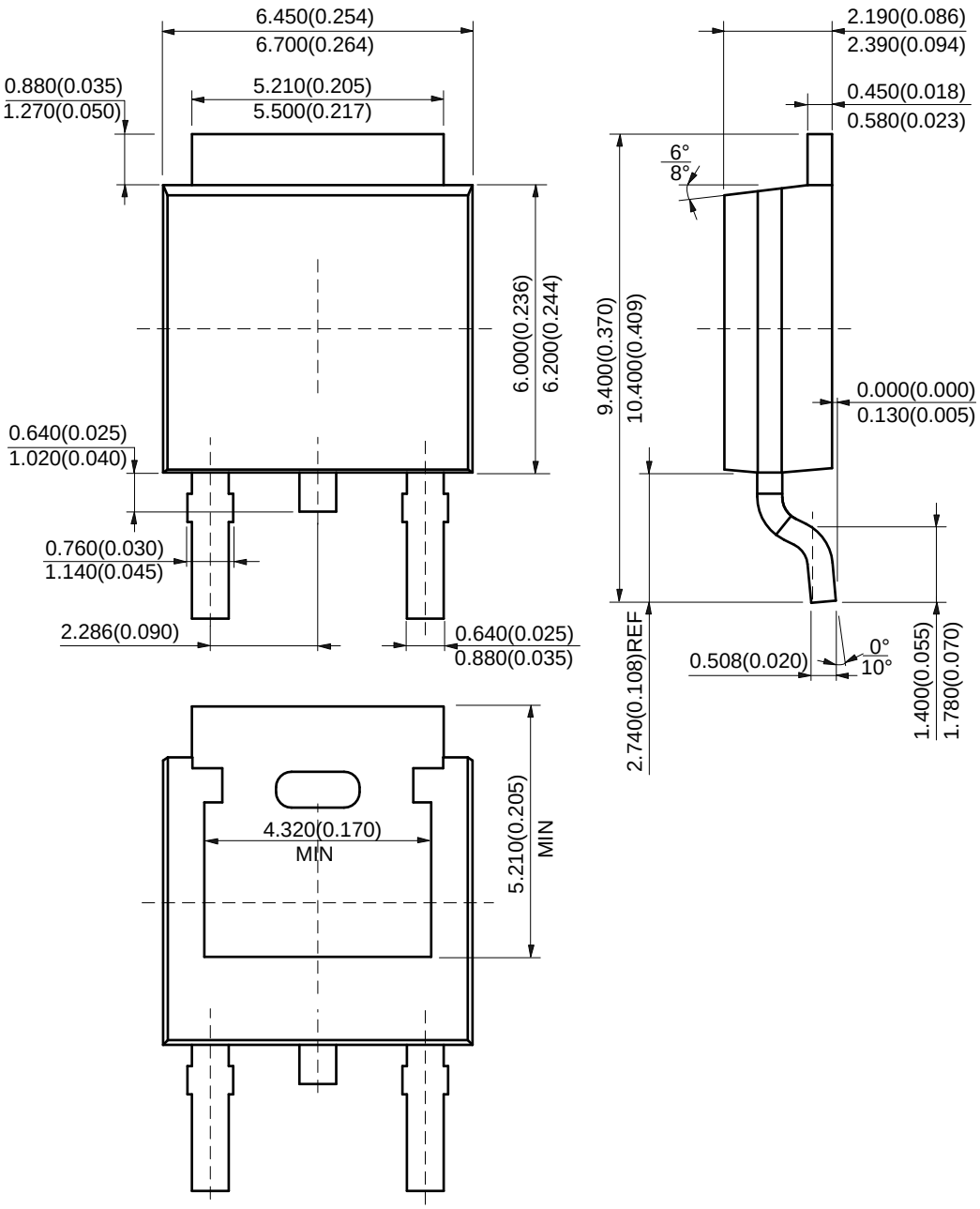
Package Outline Dimensions (All dimensions in mm)

(1) Package Type: SOT223



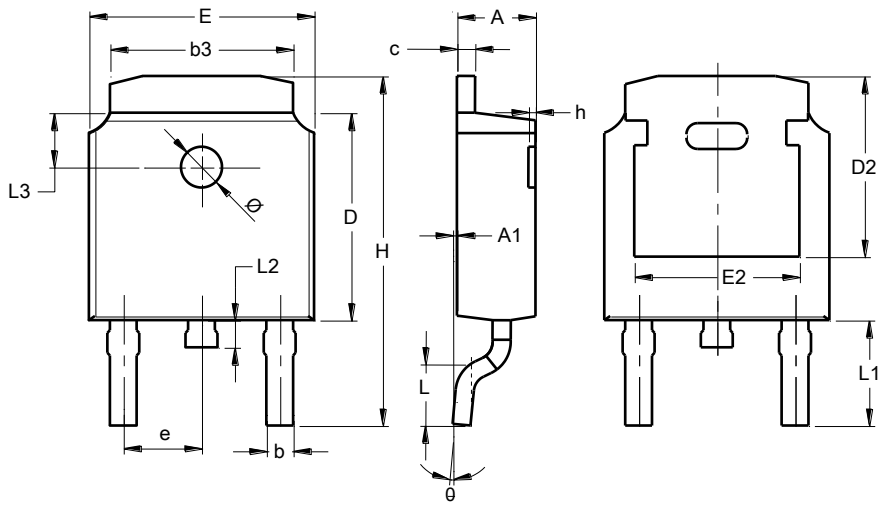
Package Outline Dimensions (All dimensions in mm) (continued)

(2) Package Type: TO252-2 (5)



Package Outline Dimensions (All dimensions in mm) (continued)

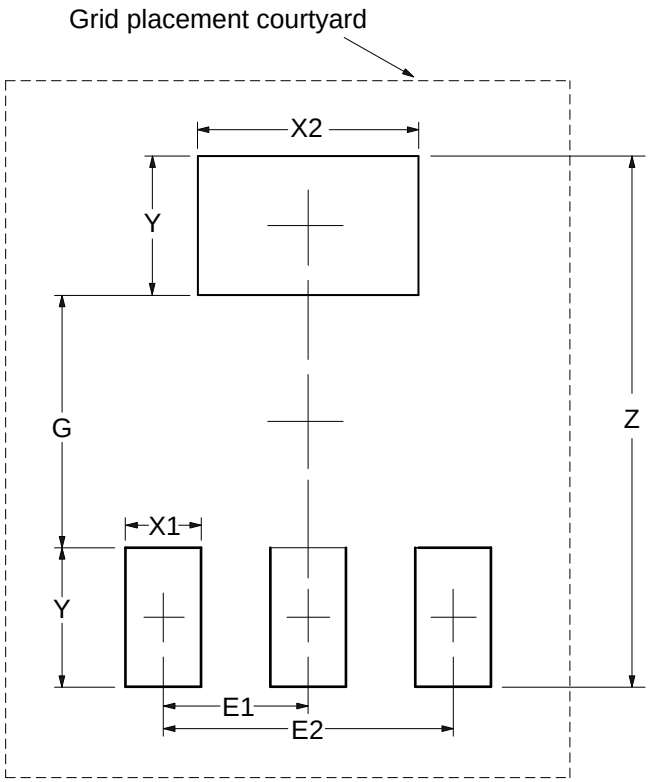
(3) Package Type : TO252 (Type CJ)



TO252 (Type CJ)			
Dim	**Min**	**Max**	**Typ**
A	2.200	2.400	--
A1	0.000	0.127	--
b	0.635	0.770	--
b3	5.100	5.460	--
c	0.460	0.580	--
D	6.000	6.200	--
D2	5.250 REF		
E	6.500	6.700	--
E2	4.830 REF		
e	2.186	2.386	--
h	0.000	0.300	--
H	9.712	10.312	--
L	1.400	1.700	--
L1	2.900 REF		
L2	0.600	1.000	--
L3	1.600 REF		
Ø	1.100	1.300	--
θ	0°	8°	--
All Dimensions in mm			

Suggested Pad Layout

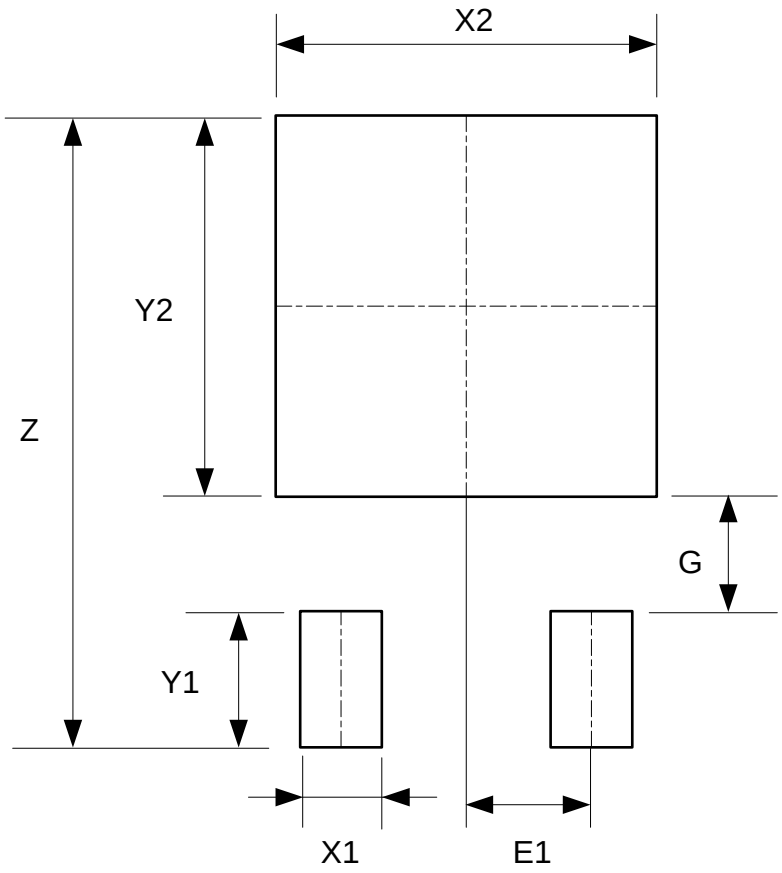
(1) Package Type: SOT223



Dimensions	Z (mm)/(inch)	G (mm)/(inch)	X1 (mm)/(inch)	X2 (mm)/(inch)	Y (mm)/(inch)	E1 (mm)/(inch)	E2 (mm)/(inch)
Value	8.400/0.331	4.000/0.157	1.200/0.047	3.500/0.138	2.200/0.087	2.300/0.091	4.600/0.181

Suggested Pad Layout (continued)

(2) Package Type: TO252-2 (5) / TO252 (Type CJ)



Dimensions	Z (mm)/(inch)	X1 (mm)/(inch)	X2=Y2 (mm)/(inch)	Y1 (mm)/(inch)	G (mm)/(inch)	E1 (mm)/(inch)
Value	11.600/0.457	1.500/0.059	7.000/0.276	2.500/0.098	2.100/0.083	2.300/0.091

Mechanical Data

- Moisture Sensitivity: Level 3 per J-STD-020
- Terminals: Finish— Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 e3
- Weight:
  - TO-252-2 / TO252 (Type CJ): 0.312 grams (Approximate)
  - SOT-223: 0.116 grams (Approximate)